

Product Qualification Report

BF776

High Performance NPN Bipolar RF Transistor

Description

This product qualification report describes the characteristics of the product with respect to quality and reliability.

The qualification sample selection was done on production lots which were manufactured and tested on standard production processes and meet the defined requirements.

The qualification test results of those products as outlined in this document are based on **JEDEC** for target applications and may reference existing qualification results of similar products. Such referencing is justified by the structural similarity of the products.

Qualification Assessment

Fully qualified according to **JEDEC** for **Industrial Applications** and assessed as PASS

For further information about comparable products, please contact the nearest Infineon Technologies office (www.infineon.com).



BF776 qualified before 2010

Package: PG-SOT343-4

MSL: 1

Electrical Stress Test Results:

Test Description	Abbr.	Condition	Duration	Lots/ss	Fail/Qty	Result
Electrical Distribution	ED	-55°C, +25°C,		1 x 30	0 / 30	PASS
		+150°C				
High Humidity High Temperature Reverse	H3TRB	T=85°C,	1000 h	4 x 60	0 / 240	PASS
Bias		RH=85%				
JESD22 A101						
High Temperature Reverse Bias	HTRB	Ta=150°C	1000 h	4 x 60	0 / 240	PASS
JESD22 A108						
Intermittend Operating Life	IOL	Tj=175°C	1000 h	4 x 60	0 / 240	PASS
MIL-STD-750 Method 1037		Cycle time:				
		2min				

Environmental Stress Test Results:

Test Description	Abbr.	Condition	Duration	Lots/SS	Fail/Qty	Result
Preconditioning	PC	Soak acc.MSL1,		4 x 240	0 / 960	PASS
J-STD020 / JESD22 A113		3x reflow, 260°C				
Temperature Cycling	TC	-55°C to +150°C	1000 cyc	4 x 60	0 / 240	PASS
JESD22 A104						
Autoclave	AC	Ta=121°C,	96 h	4 x 60	0 / 240	PASS
JESD22 A102		RH=100%				

Mechanical Stress Test Results:

Test Description	Abbr.	Condition	Duration	Lots/SS	Fail/Qty	Result
Destructive Physical Analysis	DPA	Random samples from H3TRB & TC		4/2	0/8	PASS
Physical Dimensions JESD B-100	PD			1 / 30	0/30	PASS
Resistance to Solder Heat JESD B-106	RTSH	Solder bath Ts=260°C, dip 3 x 10 sec		1 / 30	0/30	PASS
Solderability J-STD-002	SD			1 / 10	0 / 10	PASS

Notes:

Trademarks

Edition 2016-01-22
Published by
Infineon Technologies AG
81726 München, Germany

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Document reference

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